

BRCS5P06MC

Rev.A Mar.-2021

描述 / Descriptions

SOT23-3 塑封封装 P 道场效应管。

P- CHANNEL MOSFET in a SOT23 -3Plastic Package.

特征 / Features

低导通电阻，开关时间快，低导通电压，无卤产品。

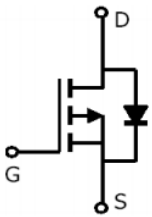
Ultra Low on-resistance, fast switching, Low on voltage, Halogen-free Product.

用途 / Applications

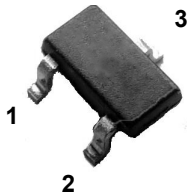
PWM 应用与负载开关。

PWM application & Load switch

内部等效电路 / Equivalent Circuit



引脚排列 / Pinning



PIN1 : G

PIN 2 : S

PIN 3 : D

印章代码 / Marking

Marking	H5P6
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极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit	
Drain-Source Voltage	V_{DSS}	-60	V	
Gate-Body Leakage Voltage	V_{GSS}	± 20	V	
Drain Current - Continuous	I_D	-5	A	
Power Dissipation (Surface Mounted on FR4 Board, $t \leq 10$ sec.)	P_D	1.5	W	
Operating and Storage Temperature Range	T_J, T_{STG}	-55~150	°C	
Maximum Junction-to-Ambient	$t \leq 10s$	$R_{\theta JA}$	118.6	°C/W
Maximum Junction-to-Ambient	Steady-State		161.6	°C/W
Maximum Junction-to-Lead	Steady-State	$R_{\theta JL}$	83.3	°C/W

电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V$ $I_D=-250\mu A$	-60	-63		V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1	-1.5	-2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V$ $I_D=-2A$		84	100	mΩ
		$V_{GS}=-4.5V$ $I_D=-1A$		103	125	mΩ
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-60V$ $V_{GS}=0V$			-1.0	μA
Gate-Body Leakage.	I_{GSS}	$V_{GS}=-20V$			-100	nA
		$V_{GS}=20V$			100	nA
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=-1A$ $T_J=25^\circ C$			-1.2	V
Input Capacitance	C_{iss}	$V_{DS}=-25V$ $V_{GS}=0V$ $f=1.0MHz$		885		pF
Output Capacitance	C_{oss}			90		
Reverse Transfer Capacitance	C_{rss}			64		
Total Gate Charge	Q_g	$V_{DS}=-30V$ $V_{GS}=-10.0V$ $I_D=-5A$		25		nC
Gate-to-Source Charge	Q_{gs}			3		
Gate-to-Drain Charge	Q_{gd}			7		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-30V$ $V_{GS}=-10V$ $R_L=7.5\Omega$ $R_G=3\Omega$		8		ns
Turn-On Rise Time	t_r			4		
Turn-Off Delay Time	$t_{d(off)}$			32		
Turn-Off Fall Time	t_f			7		

电参数曲线图 / Electrical Characteristic Curve

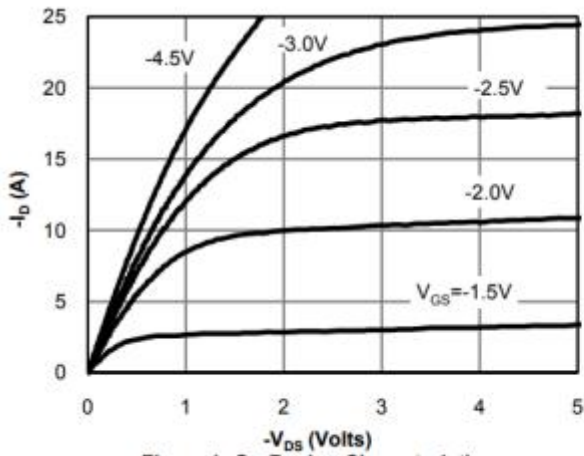


Figure 1: On-Region Characteristics

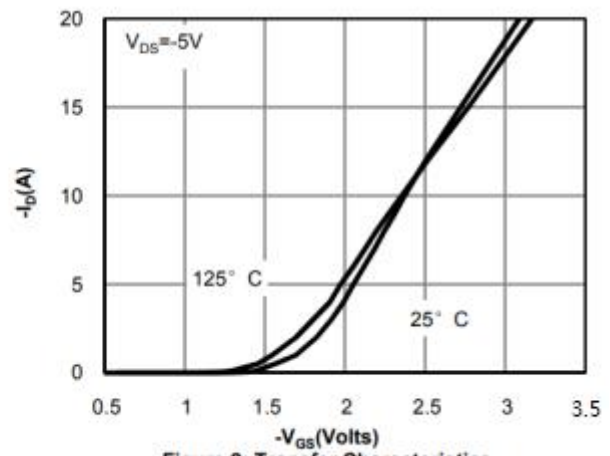


Figure 2: Transfer Characteristics

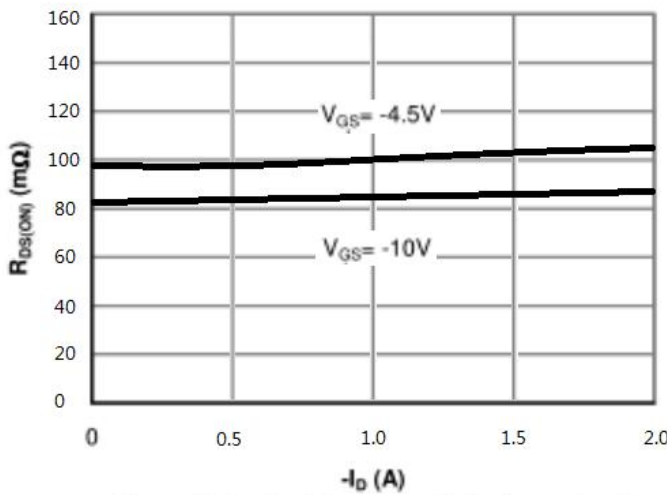


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

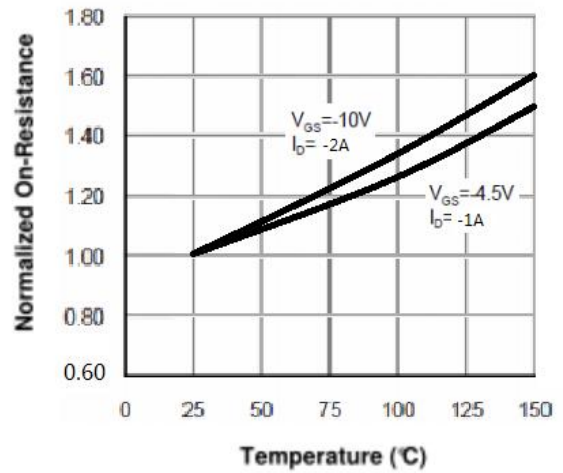


Figure 4: On-Resistance vs. Junction Temperature

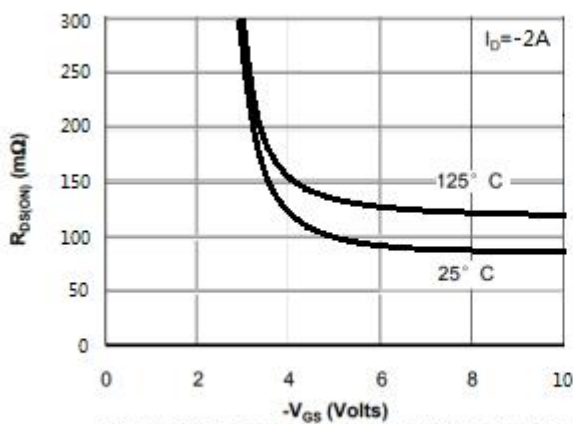


Figure 5: On-Resistance vs. Gate-Source Voltage

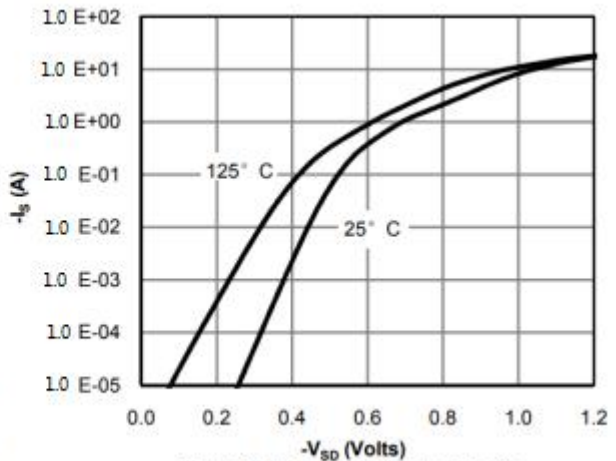


Figure 6: Body-Diode Characteristics

电参数曲线图 / Electrical Characteristic Curve

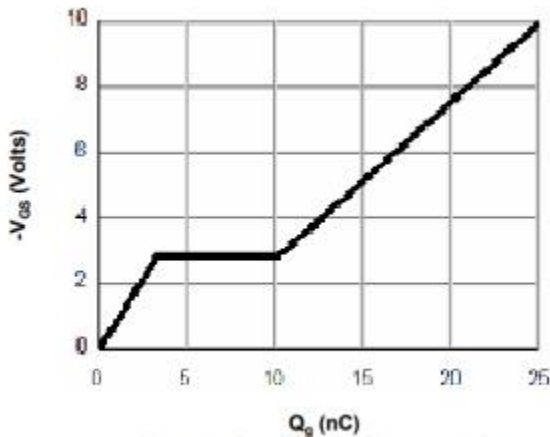


Figure 7: Gate-Charge Characteristics

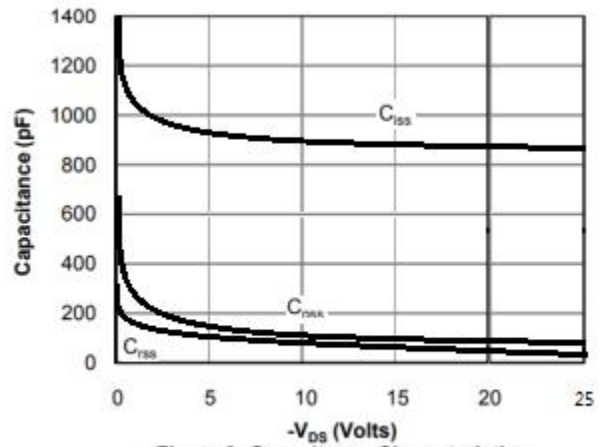


Figure 8: Capacitance Characteristics

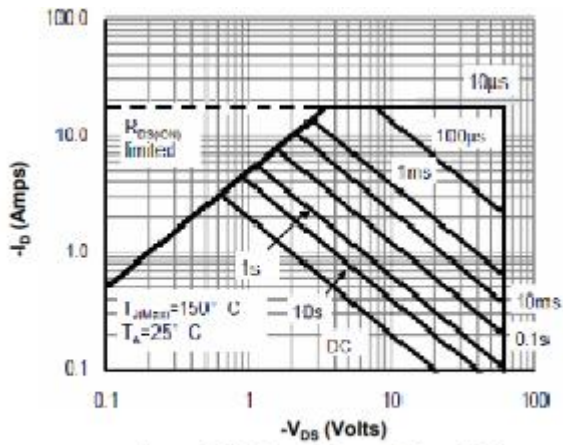


Figure 9: Maximum Forward Biased Safe Operating Area

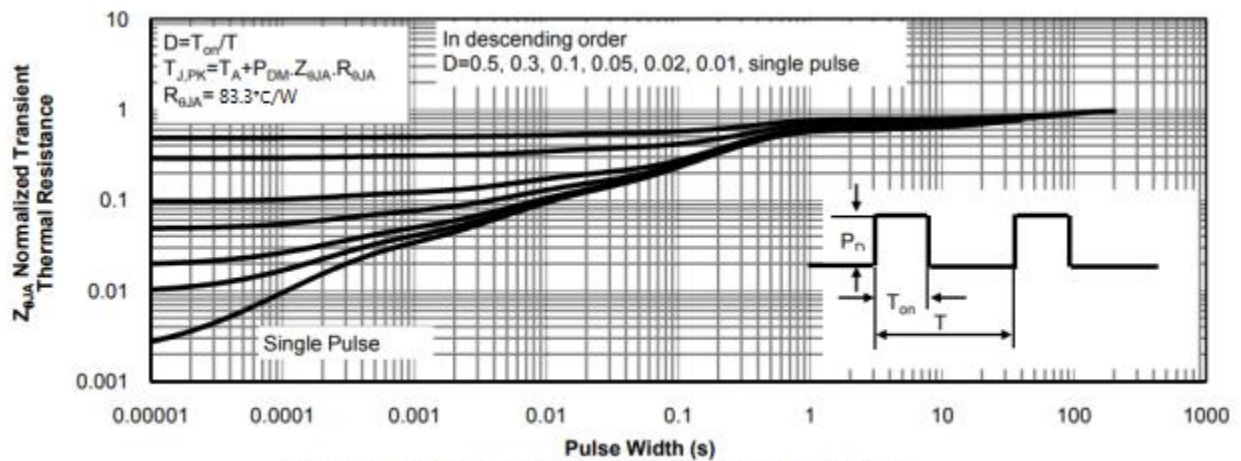
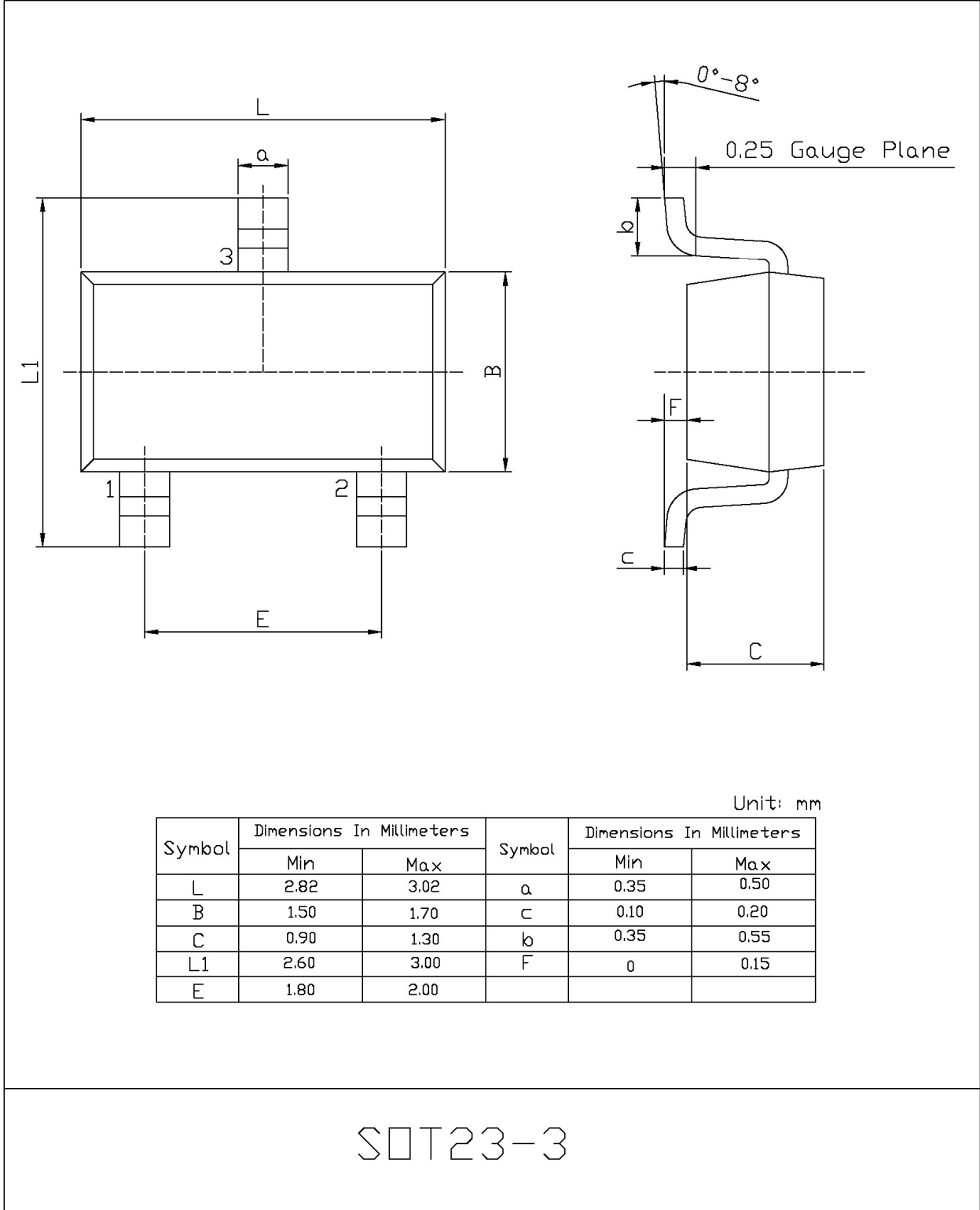
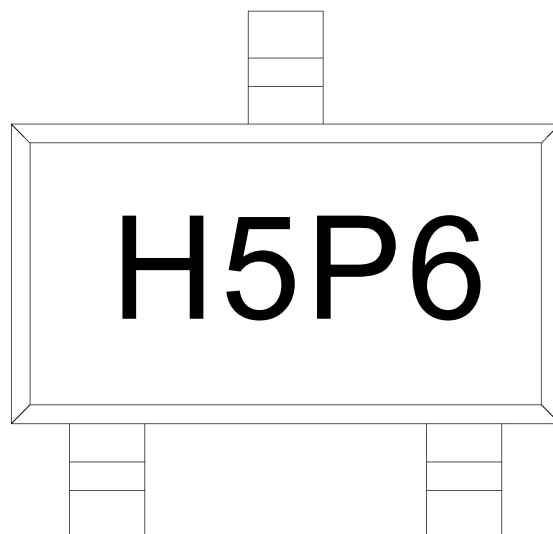


Figure 10: Normalized Maximum Transient Thermal Impedance

外形尺寸图 / Package Dimensions



印章说明 / Marking Instructions



说明：

H: 为公司代码

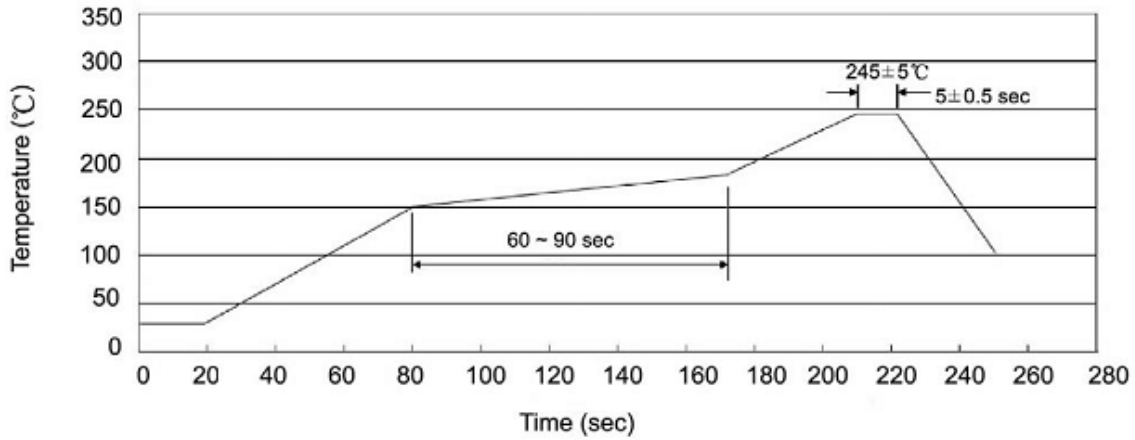
5P6 : 为型号代码

Note:

H : Company Code.

5P6: Product Type

回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)



说明：

- 1、预热温度 150 ~ 180°C，时间 60 ~ 90sec;
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

包装规格 / Packaging SPEC.

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT23-3	3,000	10	30,000	4	120,000	7" ×8	210×205×205	445×230×435

使用说明 / Notices